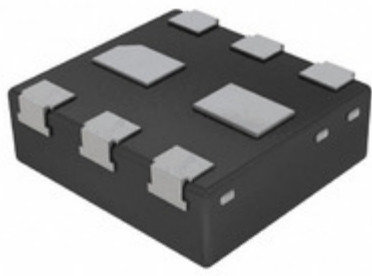

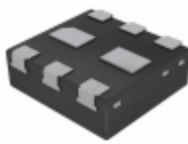
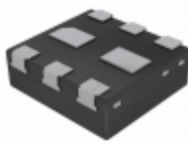
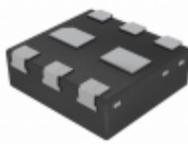
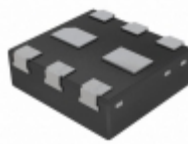
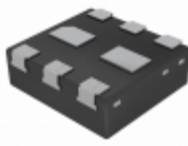
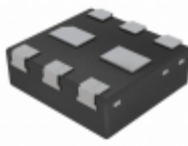
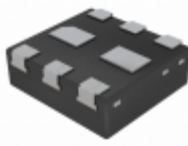
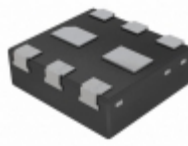
	<h2 style="color: #E67E22;">PMDXB950UPE</h2>	
	Hersteller-Teilenummer:	PMDXB950UPE
	Hersteller / Marke:	Nichicon
	Teil der Beschreibung:	MOSFET 2P-CH 20V 0.5A 6DFN
Datenblätter:	 PMDXB950UPE.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 4655 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	PMDXB950UPE
Hersteller	Nichicon
Beschreibung	MOSFET 2P-CH 20V 0.5A 6DFN
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	4655 pcs Stock
Hersteller-Teilenummer	PMDXB950UPE
Beschreibung	MOSFET 2P-CH 20V 0.5A 6DFN
Feuchtigkeitsempfindlichkeitsstufe (MSL)	1 (Unlimited)
Hersteller Standard Vorlaufzeit	6 Weeks
Expanded Beschreibung	Mosfet Array 2 P-Channel (Dual) 20V 500mA 265mW
RoHS Status	Tape & Reel (TR)
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	265mW
Polarisation	6-XFDFN Exposed Pad
Spannung - Durchschlag	6-DFN (1.1x1)
FET-Merkmal	2 P-Channel (Dual)
Drain-Source-Spannung (Vdss)	Logic Level Gate
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	20V
Rds On (Max) @ Id, Vgs	500mA
VGS (th) (Max) @ Id	1.4 Ohm @ 500mA, 4.5V
Gate Charge (Qg) (Max) @ Vgs	950mV @ 250µA
Eingabekapazität (Ciss) (Max) @ Vds	2.1nC @ 4.5V
Spannung - Prüfung	43pF @ 10V
Andere Namen	1727-1471-2




PMDXB950UPE ist neu im Original, Suche PMDXB950UPE Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie PMDXB950UPE Nichicon mit Garantie und Vertrauen.
Anfrage PMDXB950UPE: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>PMDXB600UNEZ Nichicon MOSFET 2N-CH 20V 0.6A 6DFN</p>	 <p>PMDXB950UPEZ Nexperia MOSFET 2P-CH 20V 0.5A 6DFN</p>	 <p>PMDXB1200UPEZ Nexperia MOSFET 2P-CH 30V 0.41A 6DFN</p>	 <p>PMDXB600UNELZ Nexperia 20 V, DUAL N-CHANNEL TRENCH MOSF</p>
 <p>PMDXB950UPELZ Nexperia 20 V, DUAL P-CHANNEL TRENCH MOSF</p>	 <p>PMDXB600UNE Nexperia PMDXB600UNE Nexperia USA Inc.</p>	 <p>PMDXB950UPE Nexperia MOSFET 2P-CH 20V 0.5A 6DFN</p>	 <p>PMDXB550UNEZ Nexperia MOSFET 2N-CH 30V 0.59A 6DFN</p>

heiße Teile

Mehr

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 EL2244CS	 GRM1555C1H1R7BZ01D	 HSL226KRF	 ICL7660ACBAZA-T	 IS93C46A-3GR
 LT1763CS8-1.5#TRPBF	 LTC1540IS8#TRPBF	 M1010NC450	 MCR006YZPJ910	 MZA2010D-121CT000
 P01204UC	 PMD4001K	 PMD4003K	 PMD4118OWSR	 PMD5001K
 PMD5002K	 PMD5003K	 PMD505S05HS	 PMD605S3.3HS-R1	 PMD9001D
 PMD9002D	 PMD9003D	 PMD9010D	 PMD9050D	 PMDB75T6
 PMDPB28UN	 PMDPB42UN	 PMDPB55XP	 PMDPB56XN	 PMDPB58UPE
 PMDPB65UP	 PMDPB70EN	 PMDPB70XP	 PMDPB80XP	 PMDT290UCE
 PMDT290UNE	 PMDT670UPE	 PMDXB600UNE	 PMDXB950UPE	 RS07D-M-08
 SEMIX205MLI12E4	 SGM10PA12A5V2	 SKT50A/06D	 SKY65601-477LF	 VI-J60-EX-05/S

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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